

NCS2211

Low Distortion Audio Power Amplifier with Differential Output and Shutdown Mode

Product Description

The NCS2211 is a high performance, low distortion Class A/B audio amplifier. It is capable of delivering 1 W of output power into an 8 Ω speaker bridge-tied load (BTL). The NCS2211 will operate over a wide temperature range, and it is specified for single-supply voltage operation for portable applications.

It features low distortion performance, 0.2% typical THD + N @ 1 W and incorporates a shutdown/enable feature to extend battery life. The shutdown/enable feature will reduce the quiescent current to 1 μ A maximum.

The NCS2211 is designed to operate over the -40°C to $+85^{\circ}\text{C}$ temperature range, and is available in an 8-lead SOIC package and a 3 X 3 mm DFN8 package. The SOIC package is pin compatible with equivalent function and comparable performance to competitive devices as is the DFN8 package. The DFN8 has a low thermal resistance of only $70^{\circ}\text{C}/\text{W}$ plus has an exposed metal pad to facilitate heat conduction to copper PCB material.

Low distortion, high power, low quiescent current, and small packaging makes the NCS2211 suitable for applications including notebook and desktop computers, PDA's, and speaker phones.

Features

- Differential Output
- 1.0 W into an 8 Ω Speaker
- 1.5 W into a 4 Ω Speaker
- Single Supply Operation: 2.7 V to 5.5 V
- THD+N: 0.2% @ 1 W Output
- Low Quiescent Current: 20 mA Max
- Shutdown Current < 1.0 μ A
- Excellent Power Supply Rejection
- Two Package Options: SOIC-8 Package and DFN8
- Pin Compatible with Competitive Devices
- These are Pb-Free Devices

Applications

- Desktop Computers
- Notebook Computers
- PDA's
- Speaker Phones
- Games



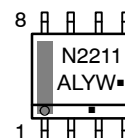
ON Semiconductor®

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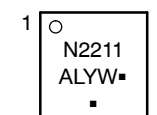
MARKING DIAGRAMS



SOIC-8
D SUFFIX
CASE 751



DFN8
MN SUFFIX
CASE 506BJ



N2211 = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT

PIN	NAME	DESCRIPTION
1	Enable	Enable (LOW)/Shutdown (HIGH)
2	Bias	Bias Output at $(V_{CC}-V_{EE})/2$; Bypass with Capacitor to Reduce Noise
3	IN+	Non-Inverting Input
4	IN-	Inverting Input
5	OUT+	Output+
6	V _{CC}	Positive Supply (Bypass with 10 μ F in parallel with 0.1 μ F)
7	V _{EE}	Negative Supply (Connect to GND for Single-Supply Operation)
8	OUT-	Output-

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

NCS2211

PIN CONNECTIONS for SOIC-8 and DFN8

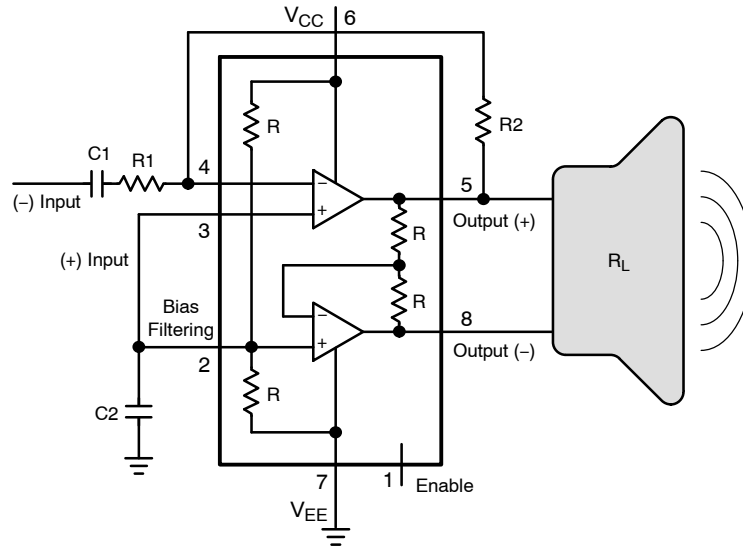
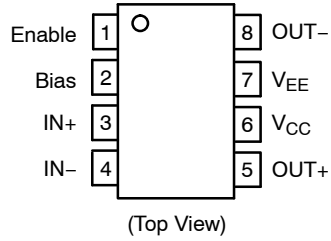


Figure 1. Block Diagram

	High	Low
Enable (Note 1)	Shutdown	Enabled

1. Enable (pin 1) must be actively driven for proper operation and cannot be left floating. See ENABLE/SHUTDOWN CONTROL in the specification table for proper logic threshold levels.

MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit
Power Supply Voltages	V_{CC}	5.5	Vdc
Output Current	I_O	500	mA
Maximum Junction Temperature (Note 2)	T_J	150	°C
Operating Ambient Temperature	T_A	-40 to +85	°C
Storage Temperature Range	T_{stg}	-60 to +150	°C
Power Dissipation	P_D	(See Graph)	mW
Thermal Resistance, Junction-to-Air – SOIC-8 – DFN8 (Note 4)	θ_{JA}	117 70	°C/W
Moisture Sensitivity (Note 3)		Level 1	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

2. Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded.

3. For additional information, see Application Note AND8003/D

4. As mounted on an 80x80x1.5 mm FR4 PCB with 650 mm² and 2 oz (0.034 mm) thick copper heat spreader. Following JEDEC JESD/EIA 51.1, 51.2, 51.3 test guidelines.

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DC ELECTRICAL CHARACTERISTICS ($V_{CC} = +5\text{ V}$, $A_{VD} = 2$, $R_L = 8\ \Omega$, $C_2 = 0.1\ \mu\text{F}$, $T_A = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Characteristics	Conditions	Min	Typ	Max	Unit
POWER SUPPLY						
V_{CC}	Operating Voltage Range		2.7		5.5	V
$I_{S, ON}$	Power Supply Current – Enabled	$V_{CC} = 2.7\text{ V to } 5.5\text{ V}$ $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ (Note 5)			20	mA
$I_{S, OFF}$	Power Supply Current – Shutdown	$V_{CC} = 2.7\text{ V to } 5.5\text{ V}$			1.0	μA
PSRR	Power Supply Rejection Ratio	$V_{CC} = 2.7\text{ V to } 5.5\text{ V}$ $T_A = -40^\circ\text{C to } +85^\circ\text{C}$		75		dB

ENABLE/SHUTDOWN CONTROL

V_{IH}	Enable Input High	Device Shutdown $V_{CC} = 2.7\text{ V to } 5.5\text{ V}$	$90\% \times V_{CC}$		V_{CC}	V
V_{IL}	Enable Input Low	Device Enabled $V_{CC} = 2.7\text{ V to } 5.5\text{ V}$	GND		$10\% \times V_{CC}$	V

OUTPUT CHARACTERISTICS

V_{OH}	Output High Voltage	From Either Output to GND $R_L = 8\ \Omega$		$V_{CC} - 0.400$		V
V_{OL}	Output Low Voltage	From Either Output to GND $R_L = 8\ \Omega$		0.400		V
$V_{out-off}$	Differential Output Offset Voltage	$V_{CC} = 2.7\text{ V to } 5.5\text{ V}$ (Note 5) $T_A = -40^\circ\text{C to } +85^\circ\text{C}$			± 50	mV
I_O	Output Current	Output to Output		350		mA

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = +5\text{ V}$, $A_{VD} = 2$, $R_L = 8\ \Omega$, $C_2 = 0.1\ \mu\text{F}$, $T_A = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Characteristics	Conditions	Min	Typ	Max	Unit
FREQUENCY DOMAIN PERFORMANCE						
GBW	Gain Bandwidth Product			12		MHz
	Phase Margin	$A_{VD} = +2$, $R_L = 8\ \Omega$, $V_{CC} = 5\text{ V}$		80		$^\circ$
THD+N	Total Harmonic Distortion	$V_{CC} = 5\text{ V}$, $f = 1\text{ kHz}$, $P = 1.0\text{ W}$ into $8\ \Omega$ $V_{CC} = 5\text{ V}$, $f = 1\text{ kHz}$, $P = 0.5\text{ W}$ into $8\ \Omega$ $V_{CC} = 3.3\text{ V}$, $f = 1\text{ kHz}$, $P = 0.35\text{ W}$ into $8\ \Omega$ $V_{CC} = 2.7\text{ V}$, $f = 1\text{ kHz}$, $P = 0.25\text{ W}$ into $8\ \Omega$		0.2 0.15 0.1 0.1		%

TIME DOMAIN RESPONSE

t_{ON}	Turn on delay	$V_{CC} = 5\text{ V}$		1		μs
t_{OFF}	Turn off delay	$V_{CC} = 5\text{ V}$		4		μs

5. Guaranteed by design and/or characterization.

TYPICAL PERFORMANCE CHARACTERISTICS

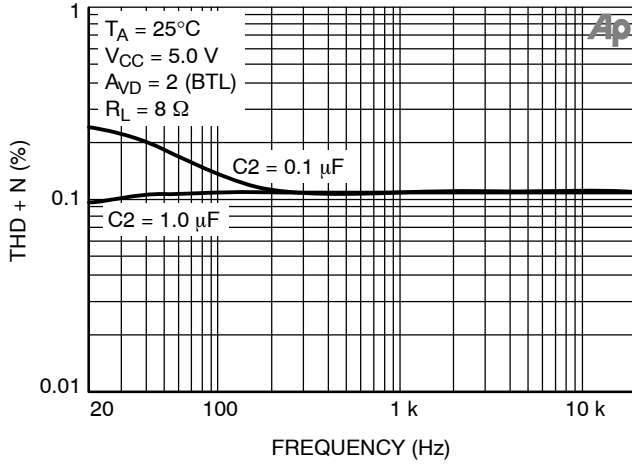


Figure 2. THD + N vs. Frequency
($P_L = 500 \text{ mW}$)

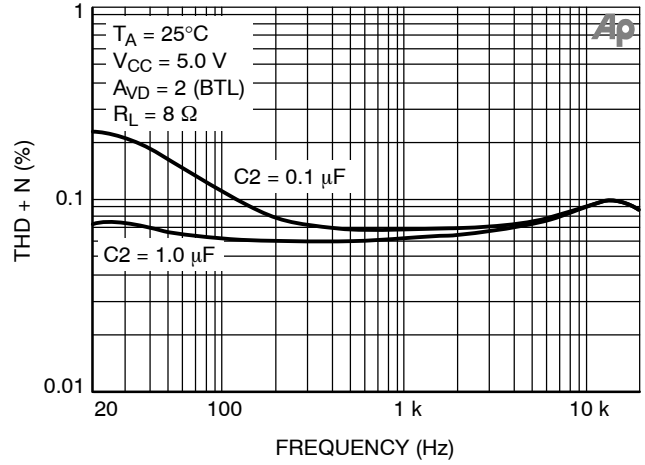


Figure 3. THD + N vs. Frequency
($P_L = 1 \text{ W}$)

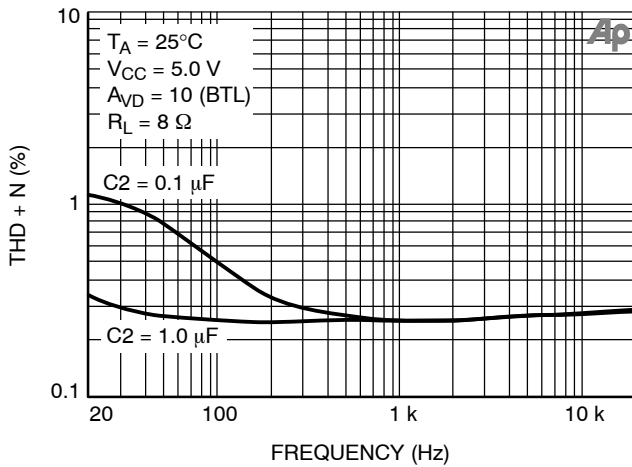


Figure 4. THD + N vs. Frequency
($P_L = 500 \text{ mW}$)

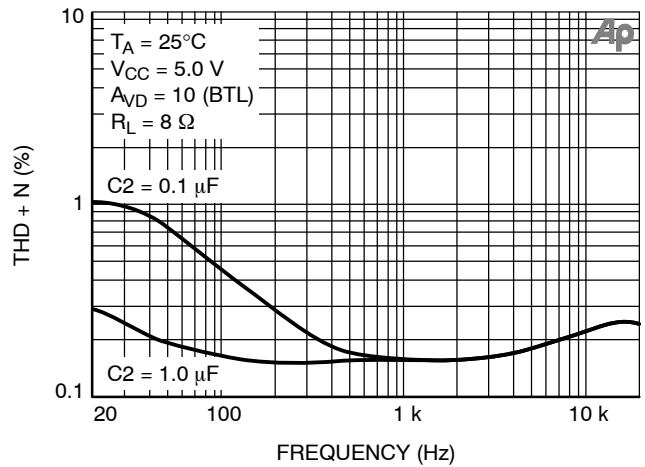


Figure 5. THD + N vs. Frequency
($P_L = 1 \text{ W}$)

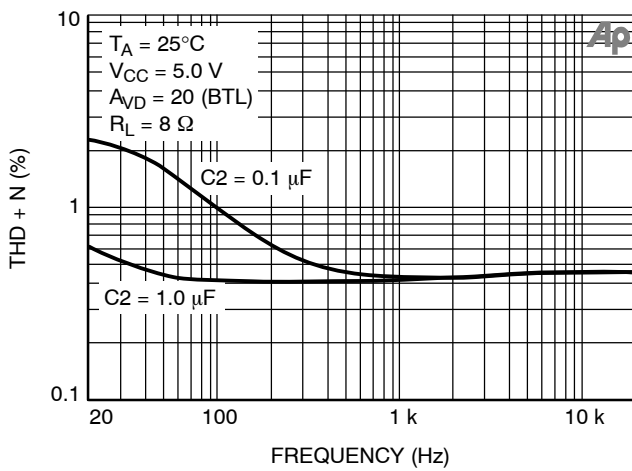


Figure 6. THD + N vs. Frequency
($P_L = 500 \text{ mW}$)

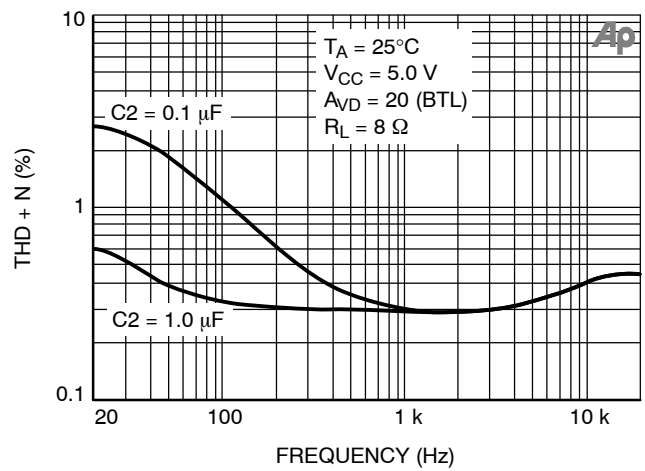


Figure 7. THD + N vs. Frequency
($P_L = 1 \text{ W}$)

TYPICAL PERFORMANCE CHARACTERISTICS

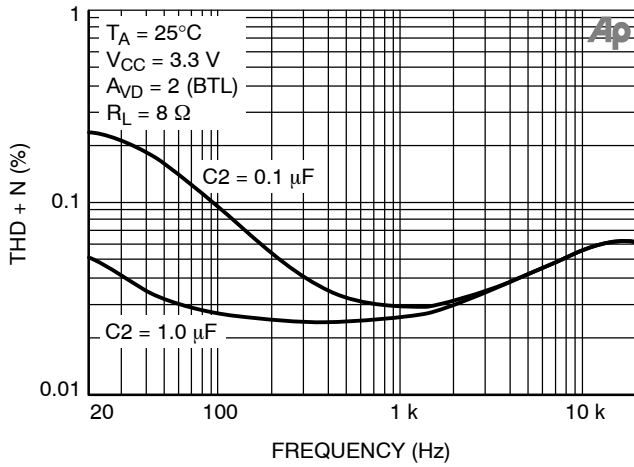


Figure 8. THD + N vs. Frequency
(P_L = 350 mW)

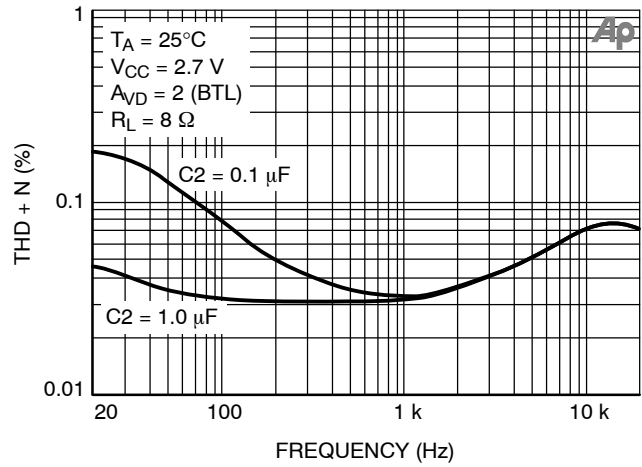


Figure 9. THD + N vs. Frequency
(P_L = 250 mW)

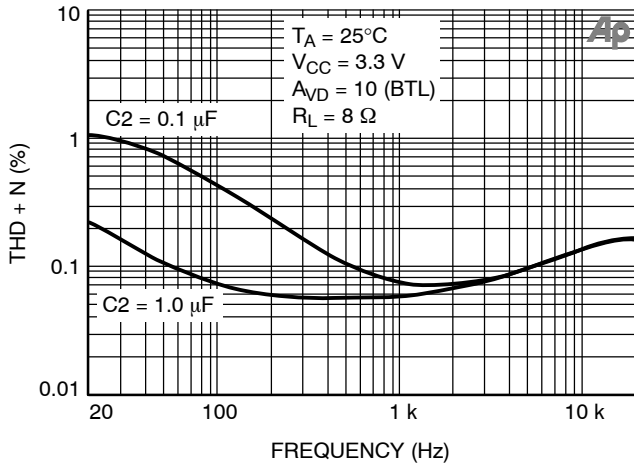


Figure 10. THD + N vs. Frequency
(P_L = 350 mW)

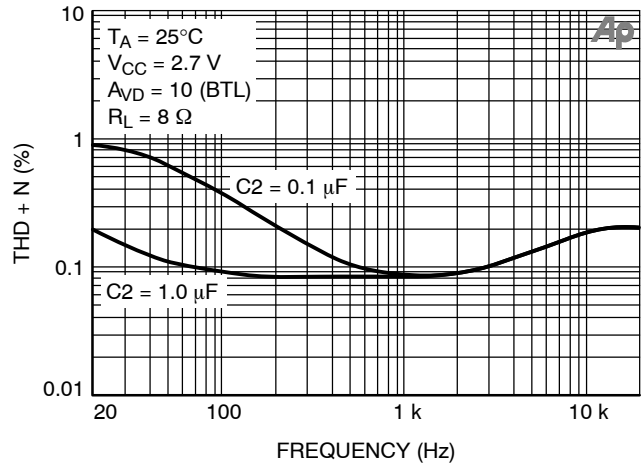


Figure 11. THD + N vs. Frequency
(P_L = 250 mW)

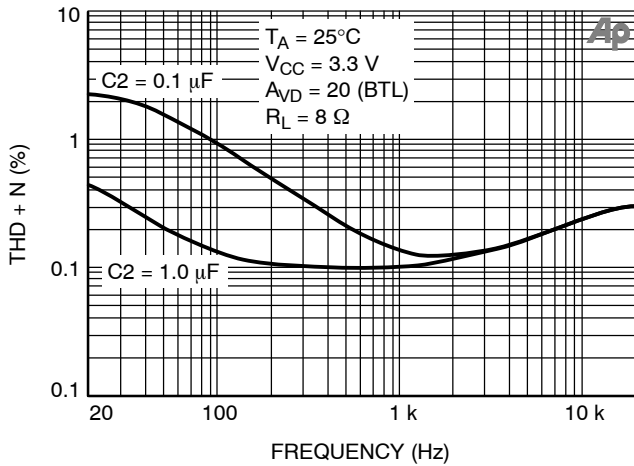


Figure 12. THD + N vs. Frequency
(P_L = 350 mW)

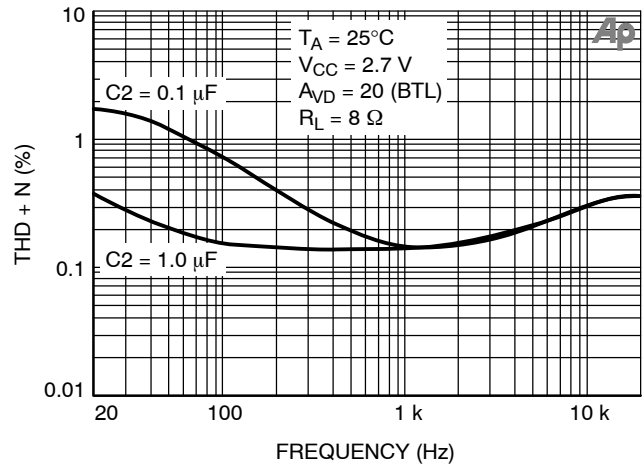


Figure 13. THD + N vs. Frequency
(P_L = 250 mW)

TYPICAL PERFORMANCE CHARACTERISTICS

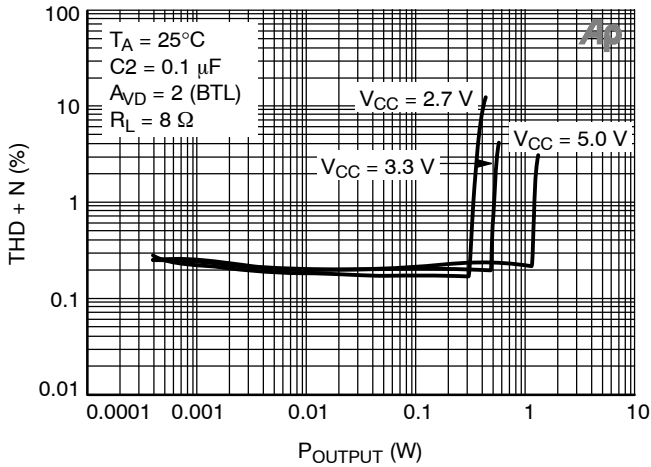


Figure 14. THD + N vs. P_{OUT}
(Frequency = 20 Hz)

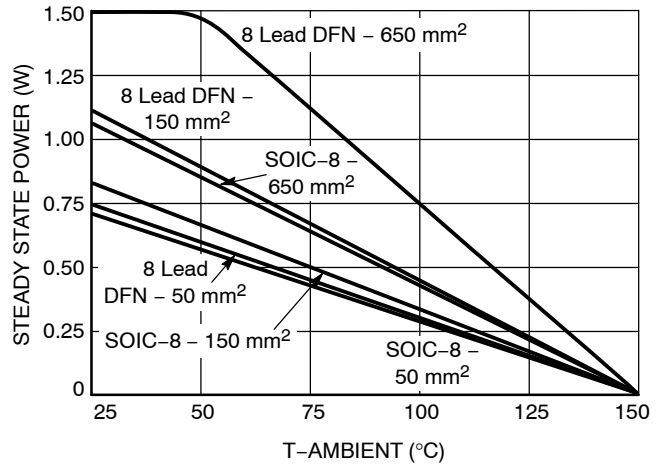


Figure 15. SOA Curve with PCB Copper Thickness 2 oz and Various Areas

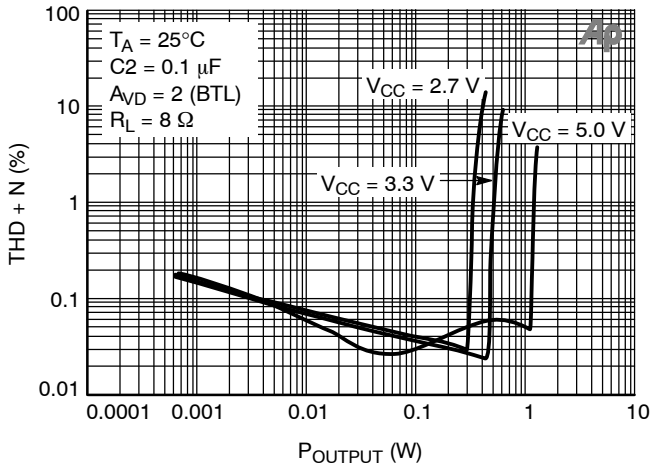


Figure 16. THD + N vs. P_{OUT}
(Frequency = 1 kHz)

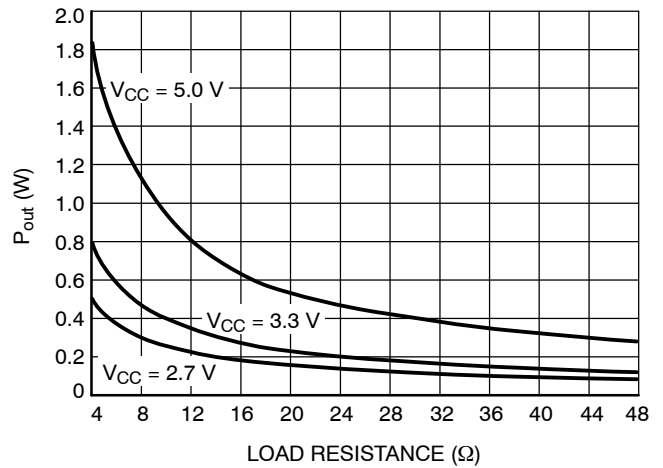


Figure 17. P_{OUT} vs. Load Resistance

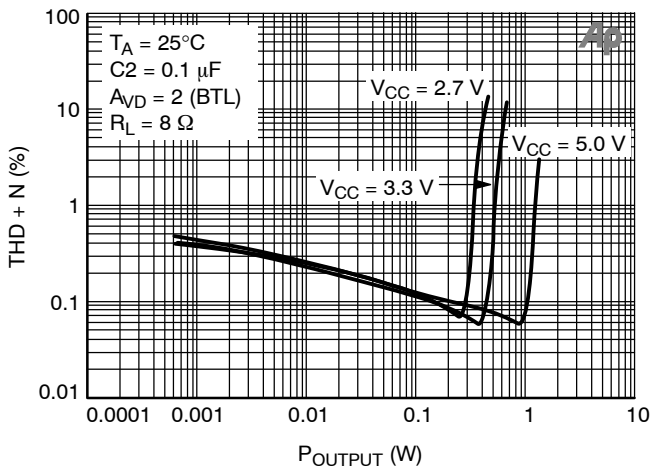


Figure 18. THD + N vs. P_{OUT}
(Frequency = 20 kHz)

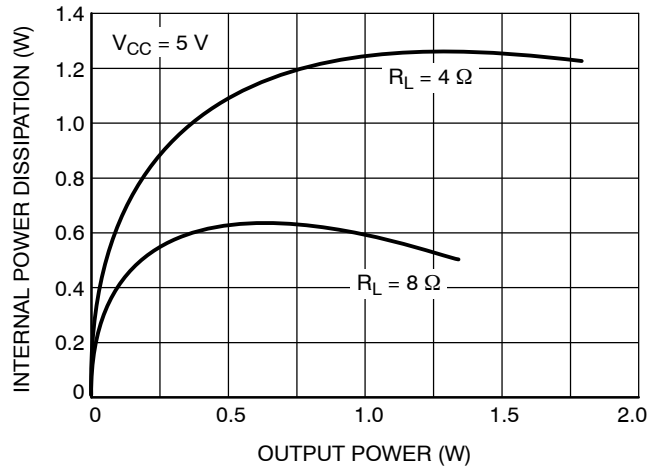


Figure 19. Power Dissipation vs. Output Power

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TYPICAL PERFORMANCE CHARACTERISTICS

Channel 1: Enable Logic and OUT+ and OUT-

Channel 2: Differential Output

Time Base: 1 μ Sec per Division



Figure 20. Turn-on Time

Channel 1: SHUTDOWN Logic and OUT+ and OUT-

Channel 2: Differential Output

Time Base: 5 μ Sec per Division

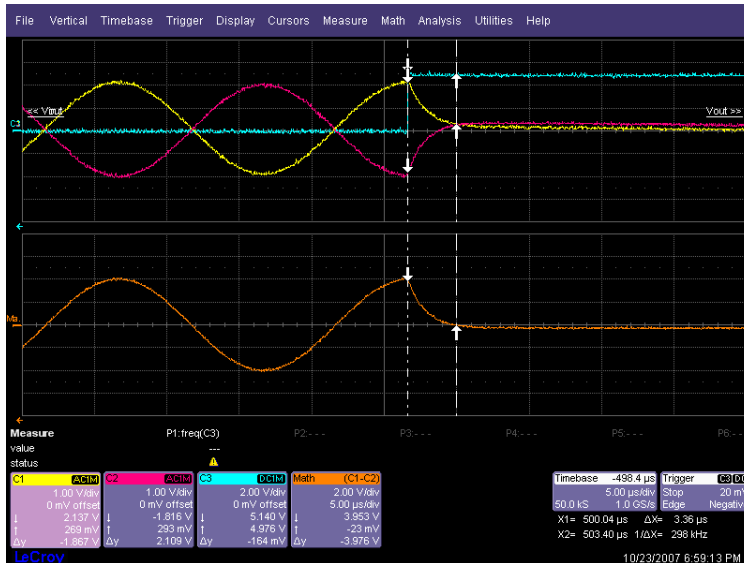


Figure 21. Turn-off Time

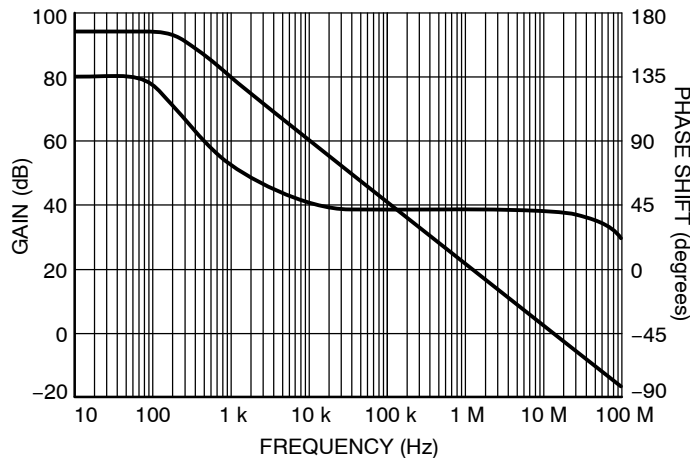


Figure 22. Gain and Phase Shift vs. Frequency

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TYPICAL PERFORMANCE CHARACTERISTICS

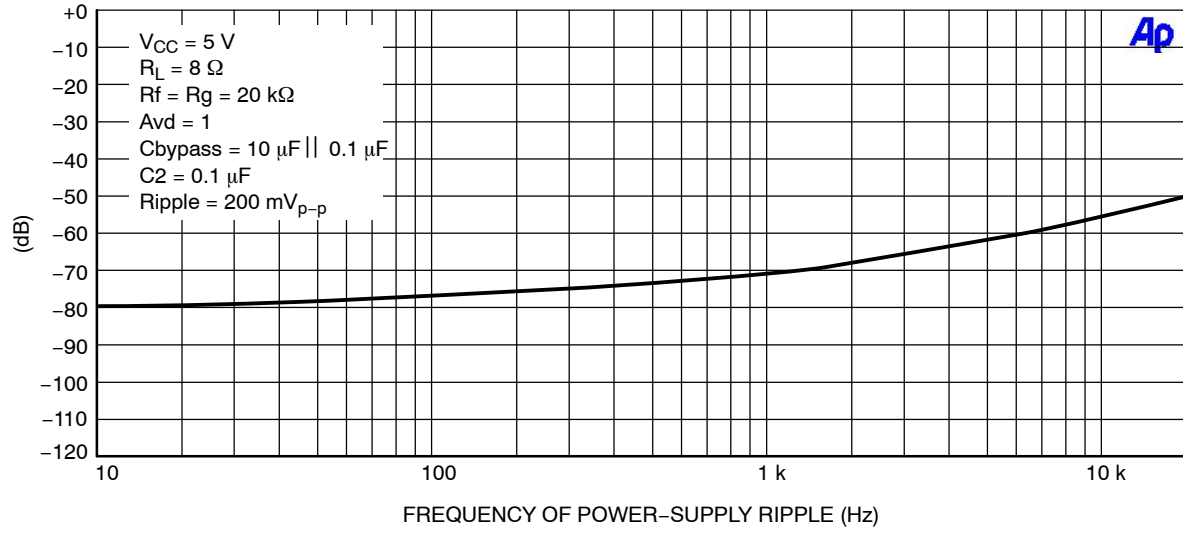


Figure 23. Power-Supply Rejection

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APPLICATIONS INFORMATION

The NCS2211 is unity gain stable and therefore does not require any compensation, but a proper power-supply bypass is required as shown in Figure 24. Performance will be enhanced by adding a filter capacitor (C2) to the mid-supply node (pin 2). See Typical Performance Characteristics for details.

It is preferable to AC couple the input to avoid a large DC output offset.

Both outputs can be driven to within 400 mV of either supply rail with an 8 Ω load.

Typical Application of the Device:

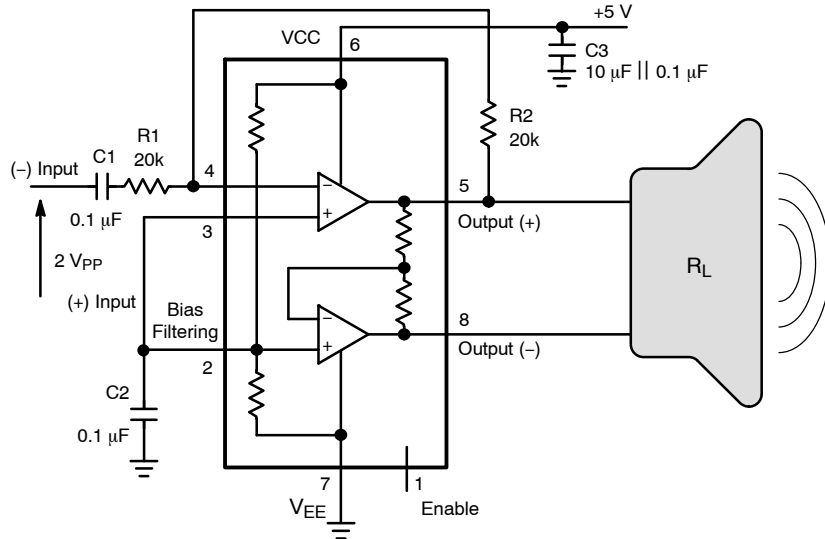


Figure 24.

THERMAL CONSIDERATIONS

Care must be taken to not exceed the maximum junction temperature of the device (150°C). Figure 15 shows the tradeoff between output power and junction temperature for different areas of exposed PCB copper (2 oz). If the maximum power is exceeded momentarily, normal circuit operation will be restored as soon as the die temperature is reduced. Leaving the device in an “overheated” condition for an extended period can result in device burnout. To ensure proper operation, it is important to observe the SOA curves.

GAIN

Since the output is differential, the gain from input to the speaker is: $A_{VD} = 2 \times R2/R1$. For low level input signals, THD will be optimized by pre-amplifying the signal and running the NCS2211 at gain $A_{VD} = 2$ and $C2=1 \mu F$.

BIAS FILTERING

Even though the NCS2211 will operate nominally with no filter capacitor on pin 2, THD performance will be improved dramatically with a filter capacitor installed (see Typical Performance Characteristics). In addition a C2 filter capacitor at pin 2 will suppress start-up popping noise. To insure optimal suppression the time constant of the bias filtering needs to be greater than the time constant of the input capacitive coupling circuit, that is $C2 \times 25 k > C1 \times R1$.

ORDERING INFORMATION

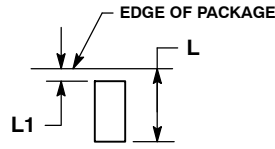
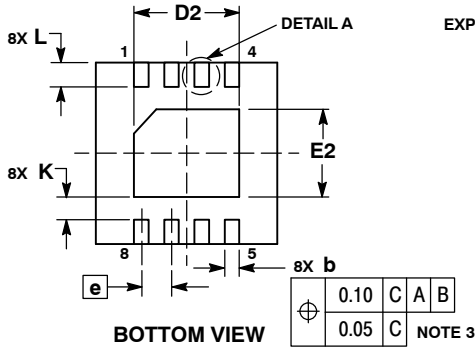
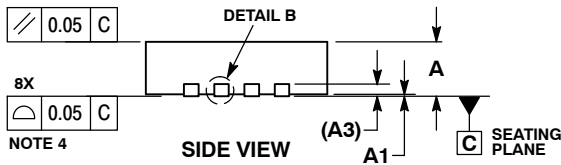
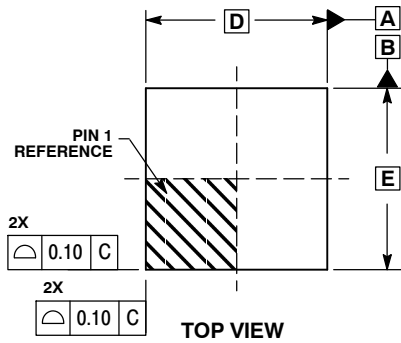
Device	Package	Shipping†
NCS2211DG	SOIC-8 (Pb-Free)	98 Units / Rail
NCS2211DR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCS2211MNTXG	DFN-8 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

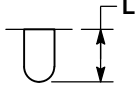
NCS2211

PACKAGE DIMENSIONS

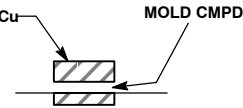
DFN8 3x3, 0.5P
CASE 506BJ-01
ISSUE O



DETAIL A
OPTIONAL
CONSTRUCTION



DETAIL A
OPTIONAL
CONSTRUCTION

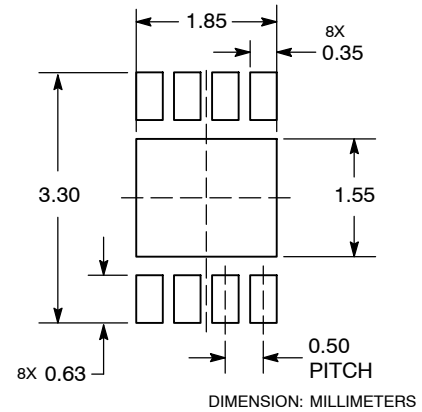


NOTES:

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	1.64	1.84
E	3.00	BSC
E2	1.35	1.55
e	0.50	BSC
K	0.20	---
L	0.30	0.50
L1	0.00	0.03

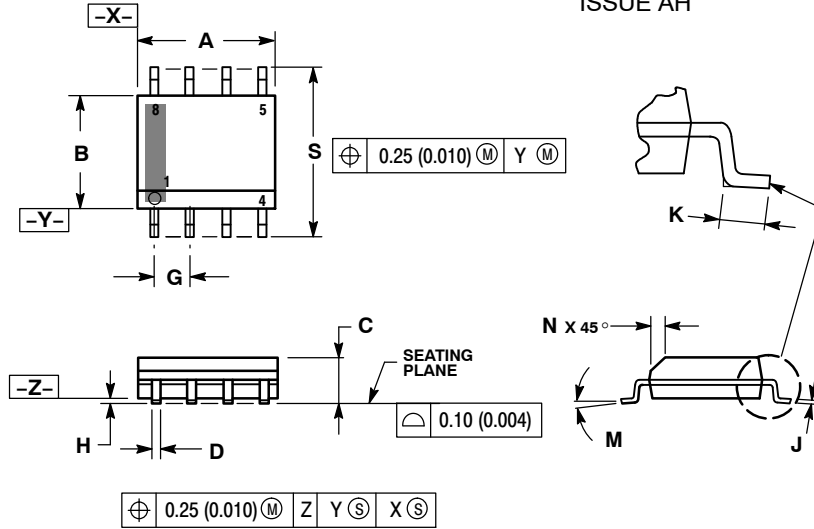
SOLDERMASK DEFINED MOUNTING FOOTPRINT



NCS2211

PACKAGE DIMENSIONS

SOIC-8 D SUFFIX CASE 751-07 ISSUE AH

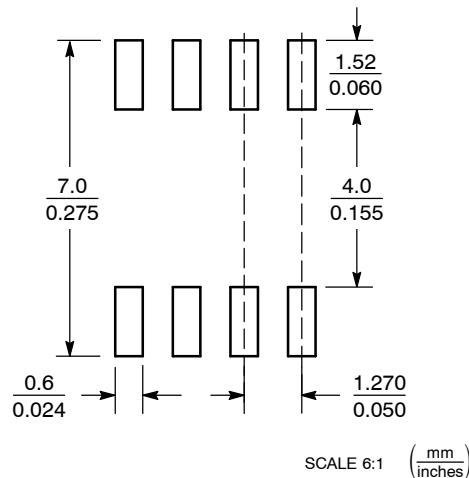


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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